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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK3900

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3900 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

• Super low on-state resistance

 $R_{DS(on)1} = 8.0 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 10 \text{ V, Ip} = 41 \text{ A)}$

 $R_{DS(on)2} = 10 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 4.5 \text{ V, Ip} = 41 \text{ A)}$

- Low Ciss: Ciss = 3500 pF TYP.
- · Built-in gate protection diode

ORDERING INFORMATION

nsistor	PART NUMBER	PACKAGE
	2SK3900-ZP	TO-263 (MP-25ZP)
	NI	(TO 262)
	400	(TO-263)
	Pic	120
	SO	
c) 🔑	,	
60	V	
+20	V	



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	V _{DSS}	60	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±82	Α
Drain Current (pulse) Note1	I D(pulse)	±246	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	104	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Energy Note2	Eas	141	mJ
Repetitive Avalanche Current Note3	Iar	37.5	Α
Repetitive Avalanche Energy Note3	Ear	141	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- **2.** Starting T_{ch} = 25°C, V_{DD} = 30 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H
- 3. Rg = 25 Ω , Tch(peak) ≤ 150 °C

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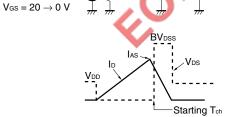
ELECTRICAL CHARACTERISTICS (TA = 25°C)

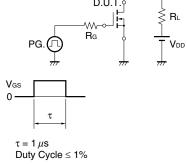
	•	•				
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 60 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 41 A	28.1	56		S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = 10 V, I _D = 41 A		6.3	8.0	mΩ
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 41 A		7.4	10	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		3500		pF
Output Capacitance	Coss	V _{GS} = 0 V		660		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		240		pF
Turn-on Delay Time	t d(on)	V _{DD} = 30 V, I _D = 41 A	•	18		ns
Rise Time	t r	V _{GS} = 10 V		11		ns
Turn-off Delay Time	t d(off)	R _G = 0 Ω		62		ns
Fall Time	t _f			5.5		ns
Total Gate Charge	Q _G	V _{DD} = 48 V		65.5		nC
Gate to Source Charge	Qgs	V _{GS} = 10 V		11.5		nC
Gate to Drain Charge	Q _{GD}	I _D = 82 A		16.5		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 82 A, V _{GS} = 0 V		0.95	1.5	V
Reverse Recovery Time	trr	IF = 82 A, VGS = 0 V		41		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		61		nC

Note Pulsed

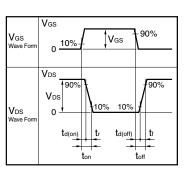
TEST CIRCUIT 1 AVALANCHE CAPABILITY

D.U.T.: $R_G = 25 \Omega$ V_{DD} P_{CD} R_{CD} R_{CD} R_{CD} R_{CD} R_{CD} R_{CD}





TEST CIRCUIT 2 SWITCHING TIME

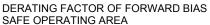


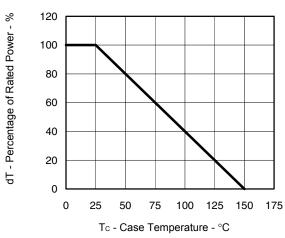
TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c} \text{D.U.T.} \\ \text{Ig} = 2 \text{ mA} \\ \text{W} \\ \text{O} \end{array} \begin{array}{c} \text{RL} \\ \text{VDD} \end{array}$$

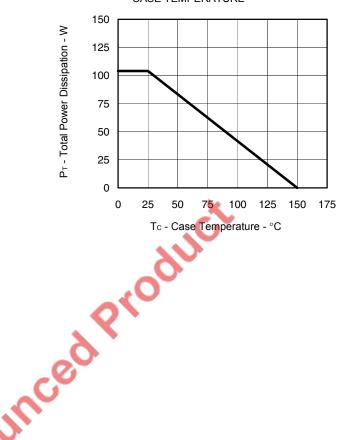


TYPICAL CHARACTERISTICS (TA = 25°C)

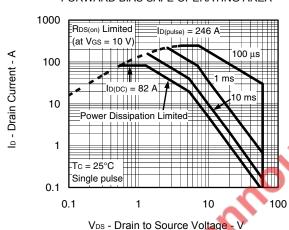




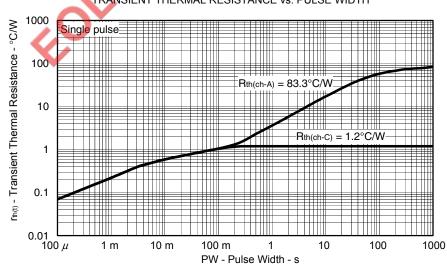
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



FORWARD BIAS SAFE OPERATING AREA



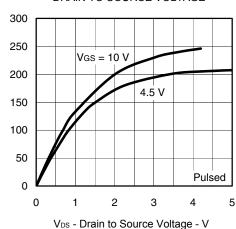
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



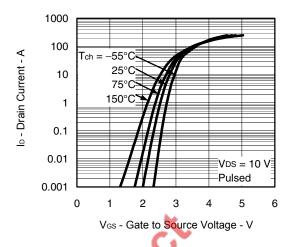
Data Sheet D17175EJ1V0DS 3

lo - Drain Current - A

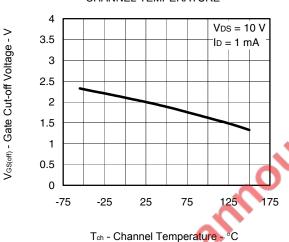
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



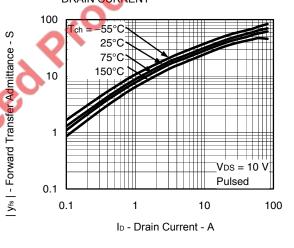
FORWARD TRANSFER CHARACTERISTICS



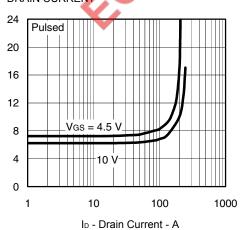
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



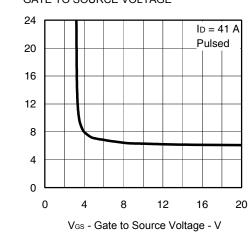
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

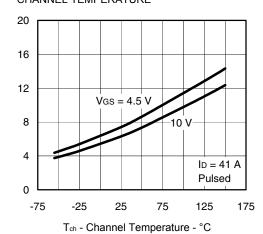


R_{DS(on)} - Drain to Source On-state Resistance - mΩ

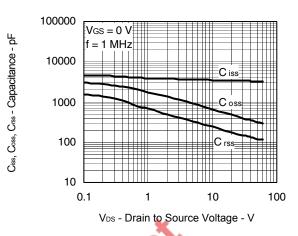
RDS(01) - Drain to Source On-state Resistance - m\Omega

R_{DS(m)} - Drain to Source On-state Resistance - mΩ

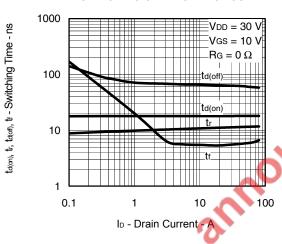
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



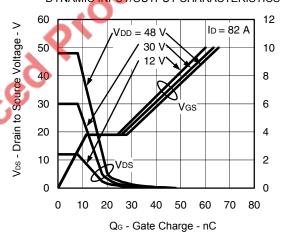
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



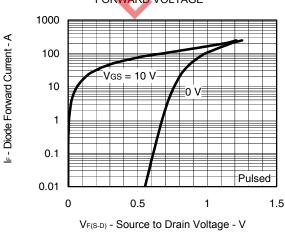
SWITCHING CHARACTERISTICS



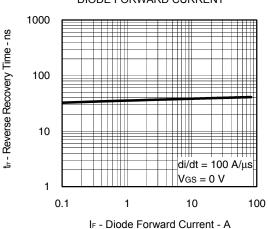
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



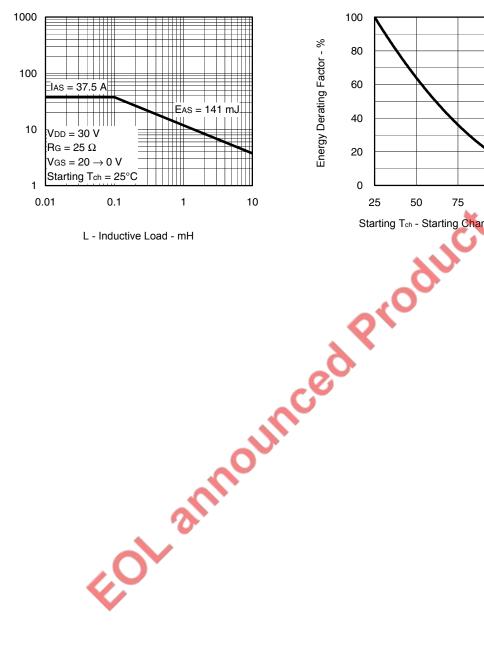
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



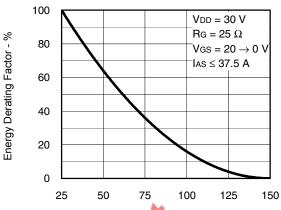
Ves - Gate to Source Voltage - V

IAS - Single Avalanche Current - A





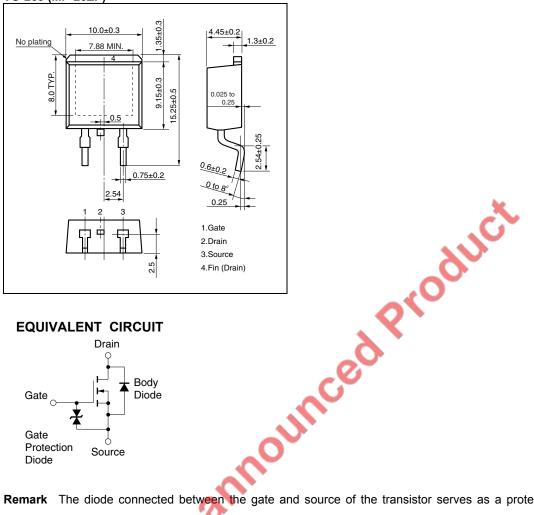
SINGLE AVALANCHE ENERGY **DERATING FACTOR**



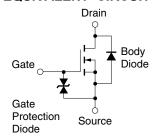
Starting Tch - Starting Channel Temperature - °C

PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZP)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

> 7 Data Sheet D17175EJ1V0DS

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